ABSOLUTE RATINGS (limiting values)

Symbol	Parameter			Value	Unit
V _{DRM} / V _{RRM}	Repetitive peak off-state voltage	Tj = 125 °C	500	V	
I _{T(RMS)}	RMS on-state current full cycle sine	Tlead = 75 °C	0.8	Α	
T(TIMO)	wave 50 to 60 Hz	<u> </u>		0.3	Α
		Tamb = 75 °C	0.8	Α	
I _{TMS}	Non repetitive surge peak on-state current	F = 50 Hz	7.3	Α	
	Tj initial = 25°C, full cycle sine wave		F = 60 Hz	8	Α
dl/dt	Critical rate of repetitive rise of on-state of	urrent	F = 120 Hz	100	A/µs
	$I_G = 20$ mA with tr = 100ns				
V_{PP}	Non repetitive line peak pulse voltage note 1			2	kV
Tstg	Storage temperature range	- 40 to + 150	°C		
Tj	Operating junction temperature range	- 30 to + 125	°C		
TI	Maximum lead temperature for soldering	during 10s		260	°C

Note 1: according to test described by IEC61000-4-5 standard & Figure 3.

SWITCH GATE CHARACTERISTICS (maximum values)

Symbol	Parameter			Unit
P _{G(AV)}	Average gate power dissipation	.0	0.1	W
I _{GM}	Peak gate current (tp = 20μs)	0/0	1	Α
V_{GM}	Peak positive gate voltage (respect to the pin COM)		5	V

THERMAL RESISTANCES

Symbol	Parameter	Value	Unit	
Rth (j-a)	Junction to ambient	TO-92	150	°C/W
		SOT-223 (*)	60	°C/W
Rth (j-l)	Junction to lead for full AC line cycle conduction	TO-92	60	°C/W
Rth (j-t)	Junction to tab for full AC line cycle conduction	SOT-223	25	°C/W

^{(*):} with 5 cm² copper (e=35µm) surface under tab

ELECTRICAL CHARACTERISTICS

For either positive or negative polarity of pin OUT voltage respect to pin COM voltage excepted note 3

Symbol	Test conditions			Values	Unit
I _{GT}	$V_{OUT} = 12V$ $R_L = 140\Omega$	Tj = 25°C	MAX.	10	mA
V _{GT}	$V_{OUT} = 12V$ $R_L = 140\Omega$	Tj = 25°C	MAX.	1	V
V_{GD}	$V_{OUT} = V_{DRM}$ $R_L = 3.3k\Omega$	Tj = 125°C	MIN.	0.15	V
IH	I _{OUT} = 100mA gate open	Tj = 25°C	TYP.	25	mA
105			MAX.	60	mA
IL IL	$I_G = 20 \text{mA}$	Tj = 25°C	TYP.	30	mA
			MAX.	65	mA
V _{TM}	$I_{OUT} = 1.1A$ tp = 500 μ s	Tj = 25°C	MAX.	1.3	V
I _{DRM} /	$V_{OUT} = V_{DRM}$	Tj = 25°C	MAX.	2	μΑ
I _{RRM}	$V_{OUT} = V_{RRM}$	Tj = 125°C	MAX.	200	μΑ
dV/dt	V _{OUT} = 400V gate open	Tj = 110°C	MIN.	500	V/µs
(dl/dt)c	(dV/dt)c = 10V/μs	Tj = 110°C	MIN.	0.1	A/ms
(dl/dt)c*	(dV/dt)c = 15V/μsI _{OUT} < 0 (note 3)	Tj = 110°C	MIN.	0.3	A/ms
V _{CL}	I _{CL} = 1mA tp = 1ms	Tj = 25°C	TYP.	600	V

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AC LINE SWITCH BASIC APPLICATION

The ACS108 device is well adapted to washing machines, dishwashers, tumble driers, refrigerators, water heaters and cookware. It has been especially designed to switch ON and OFF low power loads such as solenoids, valves, relays, dispensers, micro-motors, fans, pumps, door locks and low power lamp bulbs.

Pin COM : Common drive reference to connect to the power line neutral

Pin G : Switch Gate input to connect to the digital controller through the resistor

Pin OUT : Switch Output to connect to the load

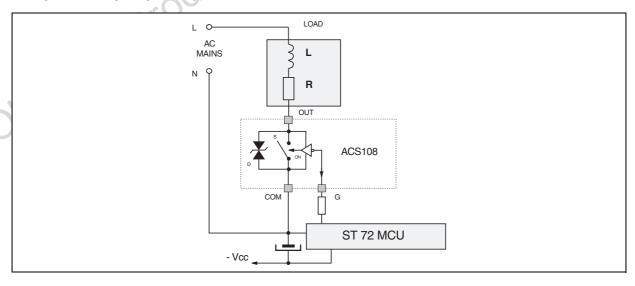
This ACS™ switch is triggered with a negative gate current flowing out of the gate pin G. It can be driven directly by the digital controller through a resistor as shown on the typical application diagram. No protection devices are required between the gates and common terminals.

The SOT-223 version allows several ACS108 devices to be connected on the same cooling PCB pad which is the COM pin: this cooling pad can be then reduced, and the printed circuit layout is simplified. In appliance systems, the ACS108 switch intends to drive low power load in full cycle ON/OFF mode. The turn off commutation characteristics of these loads can be classified in 3 groups as shown in Table 1. Thanks to its thermal and turn-off commutation characteristics, the ACS108 switch drives a load, such as door lock, lamp, relay, valve and micro motor, up to 0.2 A without any turn-off aid circuit. Switching off the ACS within one full AC line cycle will extend its current up to 0.8 A on resistive load.

Table 1: Load grouping versus their turn off commutation requirement (230V AC applications).

LOAD	Load IRMS current	POWER FACTOR	(dl/dt)c	(dV/dt)c	TURN-OFF DELAY
	(A)	FACTOR	(A/ms)	(V/µs)	(ms)
Door lock, lamp	< 0.3	1	0.15	0.15	< 10
Door lock, lamp	< 0.8	1	0.4	0.15	< 20
Relay Valve Dispenser Micro-motor	< 0.1	> 0.7	< 0.05	< 5	< 10
Pump Fan	< 0.2	> 0.2	< 0.1	< 10	< 10
i amp i an	< 0.6	> 0.2	< 0.3	< 10	< 20

TYPICAL APPLICATION DIAGRAM



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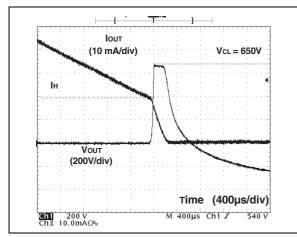
HIGH INDUCTIVE SWITCH-OFF OPERATION

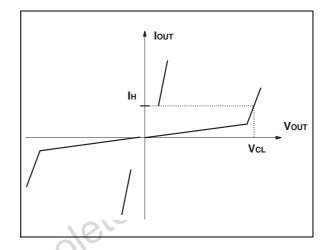
At the end of the last conduction half-cycle, the load current reaches the holding current level IH, and the ACS^{TM} switch turns off. Because of the inductance L of the load, the current flows through the avalanche diode D and decreases linearly to zero. During this time, the voltage across the switch is limited to the clamping voltage V_{Cl} .

The energy stored in the inductance of the load depends on the holding current I_H and the inductance (up to 10 H); it can reach about 20 mJ and is dissipated in the clamping section that is especially designed for that purpose.

Fig. 1: Turn-off operation of the ACS108 switch with an electro valve: waveform of the gate current IG, pin OUT current I_{OUT} & voltage V_{OUT} .

Fig. 2: ACS108 switch static characteristic.





AC LINE TRANSIENT VOLTAGE RUGGEDNESS

The ACS108 switch is able to safely withstand the AC line transient voltages either by clamping the low energy spikes or by breaking over under high energy shocks.

The test circuit in Figure 4 is representative of the final ACS™ application and is also used to stress the ACS™ switch according to the IEC61000-4-5 standard conditions. Thanks to the load, the ACS™ switch withstands the voltage spikes up to 2 kV above the peak line voltage. It will break over safely even on resistive load where the turn-on current rise is high as shown in Figure 4. Such non-repetitive testing can be done 10 times on each AC line voltage polarity.

Fig. 3: Overvoltage ruggedness test circuit for resistive and inductive loads according to IEC61000-4-5 standard.

 $R = 150\Omega$, $L = 5\mu H$, $V_{PP} = 2kV$.

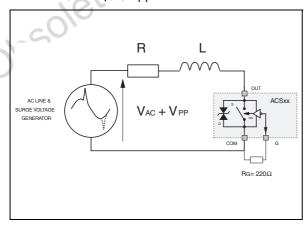
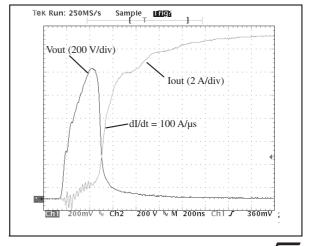


Fig. 4: Current and voltage of the ACS[™] during IEC61000-4-5 standard test with a 150Ω - 10μH load & V_{PP} = 2kV.



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Fig. 5: Maximum power dissipation versus RMS on-state current.

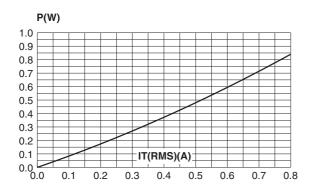


Fig. 7-1: Relative variation of thermal impedance junction to ambient versus pulse duration (ACS108-5SA) (TO-92).

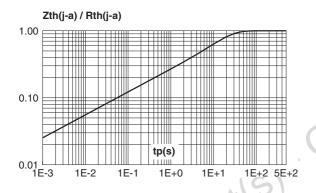


Fig. 8: Relative variation of gate trigger current versus junction temperature.

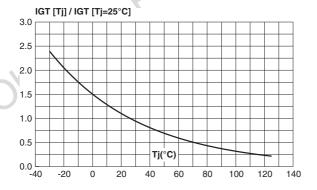


Fig. 6: RMS on-state current versus ambient temperature.

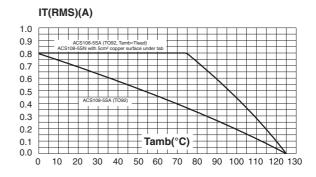


Fig. 7-2: Relative variation of thermal impedance junction to ambient versus pulse duration (ACS108-5SN) (SOT-223).

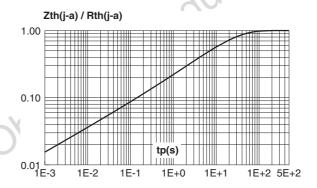
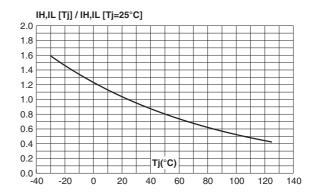


Fig. 9: Relative variation of holding and latching current versus junction temperature.



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Fig. 10: Non repetitive surge peak on-state current versus number of cycles.

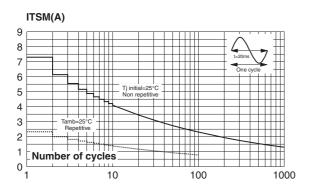


Fig. 12: On-state characteristics (maximum values).

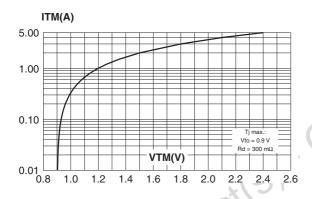


Fig. 14: Relative variation of critical (dl/dt)c versus junction temperature.

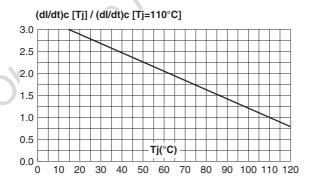


Fig. 11: Non-repetitive surge peak on-state current for a sinusoidal pulse with width tp < 10ms, and corresponding value of I^2 t.

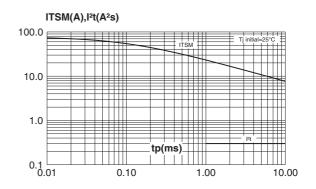
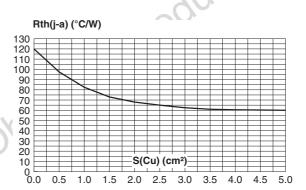
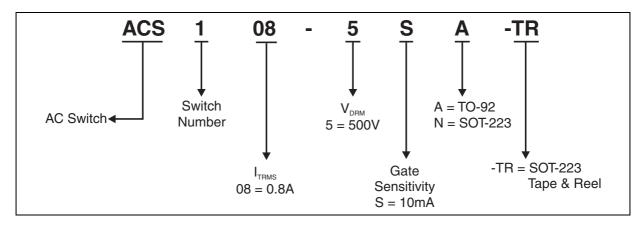


Fig. 13: Thermal resistance junction to ambient versus copper surface under tab (Epoxy printed circuit board FR4, copper thickness: 35μm).



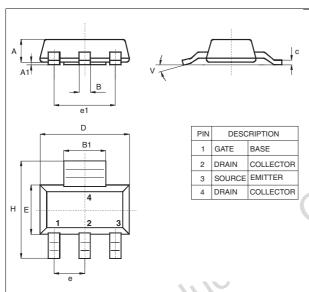
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ORDERING INFORMATION



PACKAGE MECHANICAL DATA

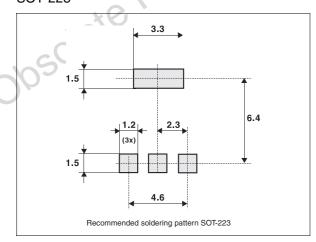
SOT-223



			DIMEN	ISIONS	.10	
REF.	Mi	Millimeters		Inches		
	Min.	Тур.	Max.	Min.	Тур.	Max.
Α			1.80	0		0.071
A1	0.02		0.10	0.001		0.004
В	0.60	0.70	0.85	0.024	0.027	0.033
B1	2.90	3.00	3.15	0.114	0.118	0.124
С	0.24	0.26	0.35	0.009	0.010	0.014
D	6.30	6.50	6.70	0.248	0.256	0.264
е		2.3			0.090	
e1		4.6			0.181	
Е	3.30	3.50	3.70	0.130	0.138	0.146
Н	6.70	7.00	7.30	0.264	0.276	0.287
V	10° max					

PACKAGE MECHANICAL DATA

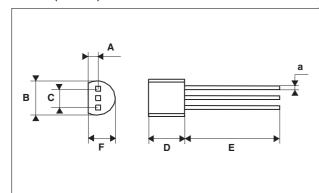
SOT-223



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PACKAGE MECHANICAL DATA

TO-92 (Plastic)



	DIMENSIONS					
REF.	Mi	Millimeters Inches		Millimeters Inches		i
	Min.	Тур.	Max.	Min.	Тур.	Max.
Α		1.35			0.053	
В			4.70			0.185
С		2.54			0.100	
D	4.40			0.173		
Е	12.70			0.500		
F			3.70			0.146
а			0.45			0.017

OTHER INFORMATION

Ordering type	Marking	Package	Weight	Base qty	Delivery mode
ACS108-5SA	ACS108/5S	TO-92	0.2 g	2500	Bulk
ACS108-5SA-TR	ACS108/5S	TO-92	0.2 g	2000	Tape & reel
ACS108-5SN	ACS1/085S	SOT-223	0.12 g	1000	Tape & reel

REVISION HISTORY

ACS 106-551V	ACS 1/0855	501-223	0.12 g	1000	таре & геег	
REVISION HISTORY						
Date	Revision	Description of Changes				
Apr-2004	1	First Issue	0/-			
21-Jun-2005	2	Marking informatio	n updated from	ACSxxxx t	o ACS1xxx	
formation furnished is belie	eved to be accurate and re	iable. However, STMicroo	electronics assumes	no responsibilit	ry for the consequences	

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